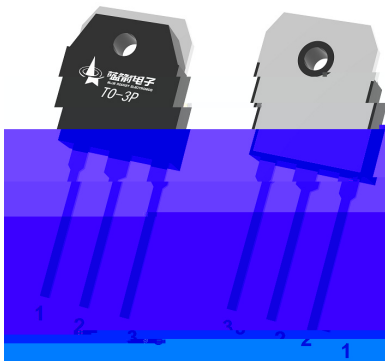
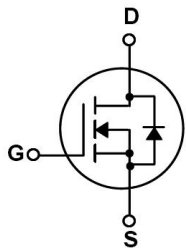


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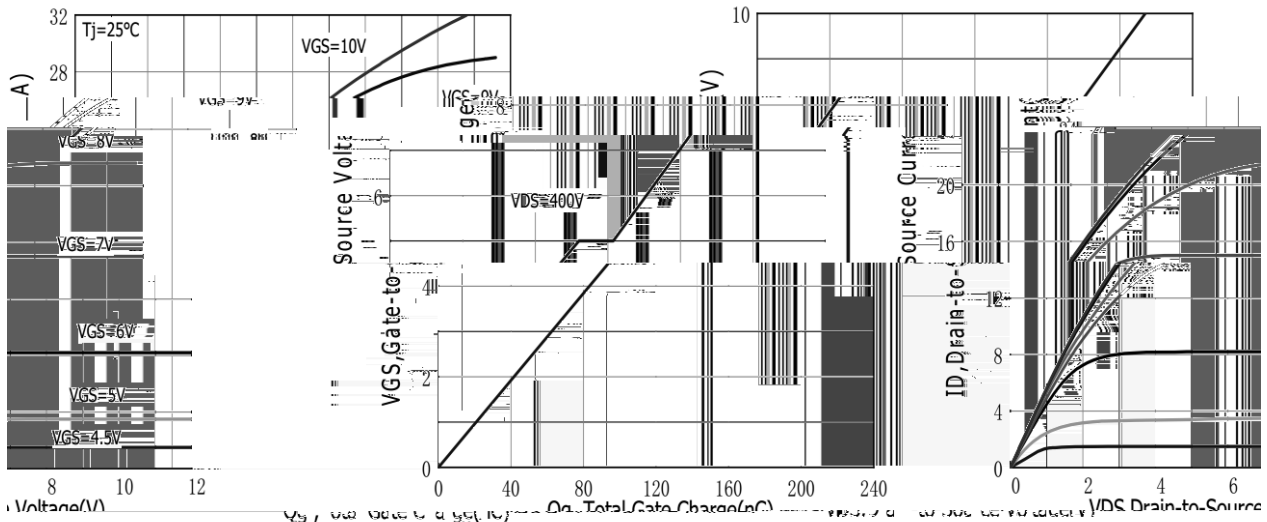




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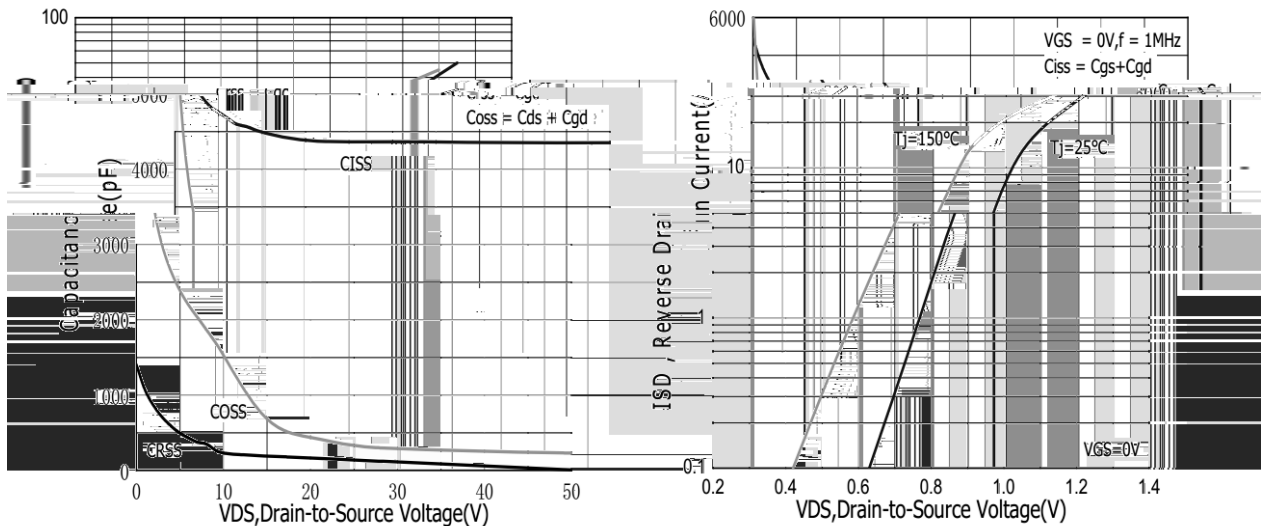


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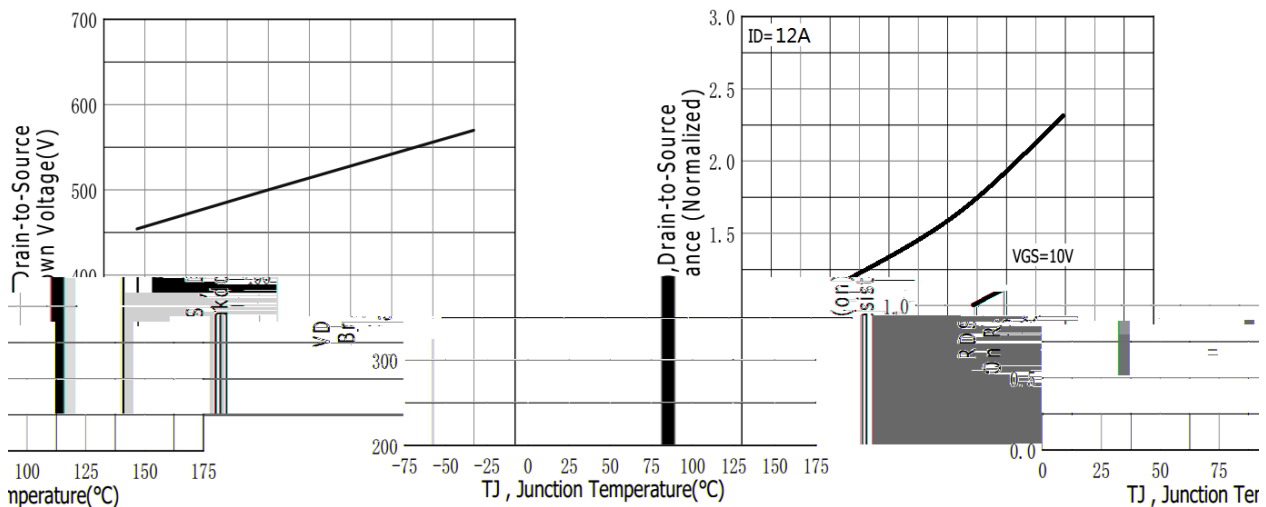
2. Typical Gate Charge vs Gate to Source Voltage

1. Typical Output Characteristics



4. Typical Capacitance vs Drain to Source Voltage

3. Typical Body Diode Transfer Characteristics



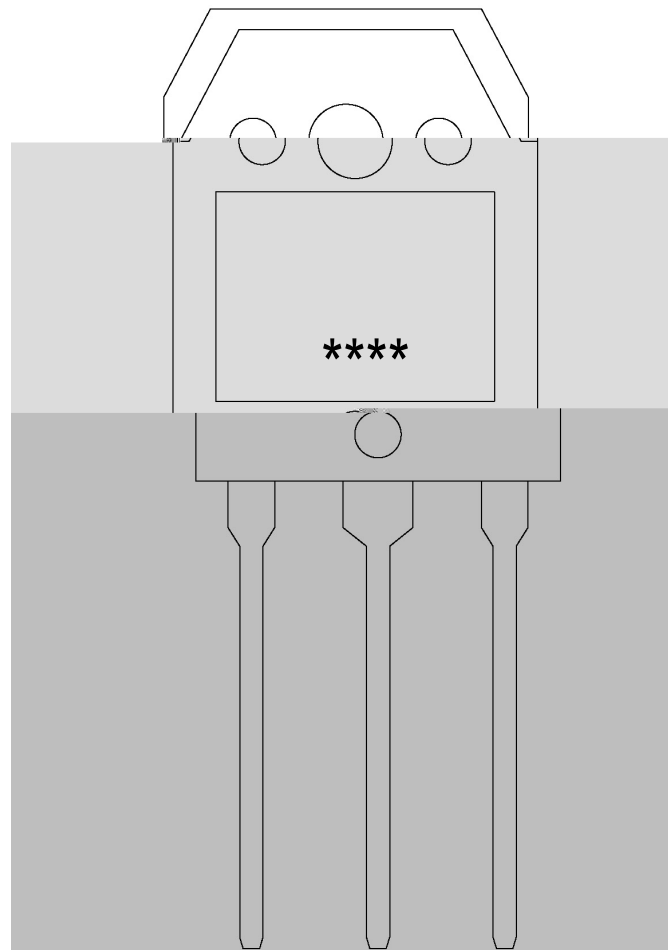
4. Typical Drain-to-Source On-Resistance vs Junction Temperature

5. Typical Breakdown Voltage vs Junction Temperature

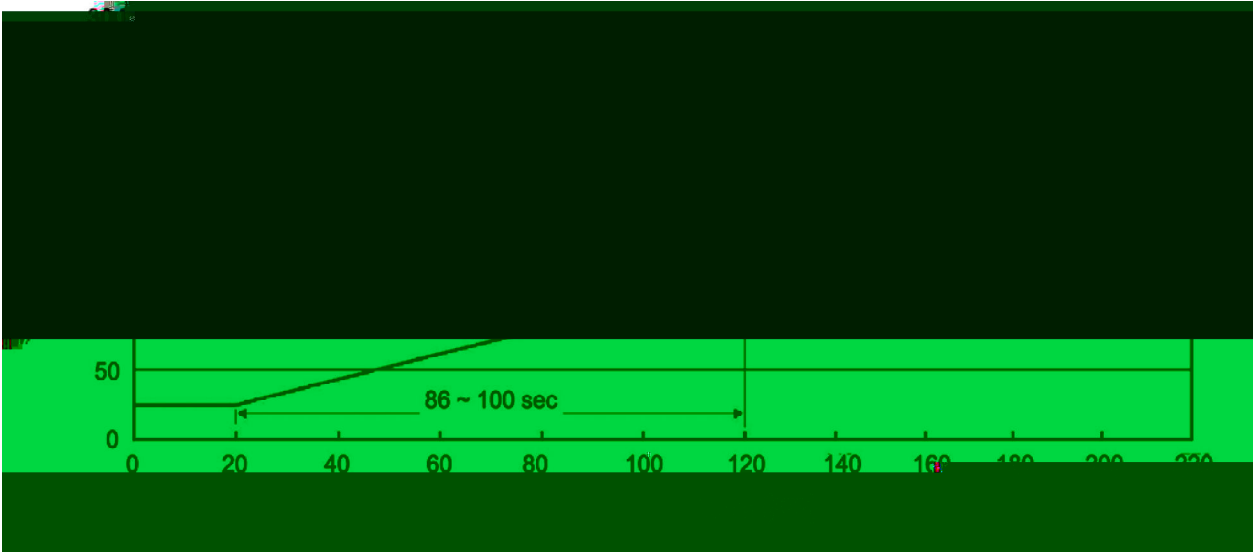
6. Typical

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